



Name :

Roll No. :

Invigilator's Signature :

**CS/B.Tech(OLD)/SEM-2/EC-201/2012
2012**

BASIC ELECTRONICS ENGINEERING

Time Allotted : 3 Hours

Full Marks : 70

The figures in the margin indicate full marks.

*Candidates are required to give their answers in their own words
as far as practicable.*

GROUP – A

(Multiple Choice Type Questions)

1. Choose the correct alternatives for any *ten* of the following :
 $10 \times 1 = 10$
- i) Current flows in a semiconductor depends on the phenomenon of
 - a) drift
 - b) diffusion
 - c) recombination
 - d) all of these.
 - ii) Doping materials are called impurities because they
 - a) decrease the number of charge carriers
 - b) change the chemical properties of semiconductors
 - c) make semiconductors less than 100 percent pure
 - d) alter the crystal structures of the pure semiconductors.
 - iii) Avalanche breakdown is primarily dependant on the phenomenon of
 - a) collision
 - b) doping
 - c) ionization
 - d) recombination.
 - iv) When a transistor is fully switched ON, it is said to be
 - a) saturated
 - b) cut-off
 - c) critical
 - d) complemented.



- v) The *d.c.* load line of a transistor circuit
 - a) has a negative slope
 - b) is a curved line
 - c) gives graphic relation between I_C and I_B
 - d) does not contain the *Q* point.
- vi) The *h*-parameters of a transistor depend on is
 - a) configuration
 - b) operating point
 - c) temperature
 - d) all of these.
- vii) When same input signal is applied to both the inputs of an ideal diff-amp, the output
 - a) is zero
 - b) depends on its CMRR
 - c) depends on its voltage gain
 - d) is determined by its symmetry.
- viii) Negative feedback in an amplifier
 - a) lowers its lower 3-dB frequency
 - b) raises its upper 3-dB frequency
 - c) increases its value
 - d) all of these.
- ix) The extremely high input impedance of a MOSFET is primarily due to the
 - a) absence of its channel
 - b) negative gate-source voltage
 - c) depletion of current carriers
 - d) extremely small leakage current of its gate capacitor.
- x) A DIAC is equivalent to a
 - a) pair of SCRs
 - b) pair of four-layer SCRs
 - c) diode and two resistors
 - d) TRIAC with two gates.



- xi) Since input resistance of an ideal OP-AMP is infinite
 - a) its output resistance is zero
 - b) its output voltage becomes independent of load resistance
 - c) its input current is zero
 - d) it becomes a current-controlled device.
- xii) The signal to be observed on the screen of an oscilloscope is applied
 - a) across its X-plates
 - b) across its Y-plates
 - c) to the horizontal amplifier
 - d) to the trigger circuit.
- xiii) Major part of the current in an intrinsic semiconductor is due to
 - a) conduction-band electrons
 - b) valence-band electrons
 - c) holes in the valence band
 - d) thermally-generated electron.

GROUP - B

(Short Answer Type Questions)

Answer any *three* of the following. $3 \times 5 = 15$

2. Draw the structure of an n -channel JFET and explain its principle of operation.
3. What are "lissajous figures" ? How can they be displayed on CRO screen ?
4. Explain zener breakdown. Draw a circuit for operating zener diode.
5. A single-phase half-wave rectifier using a 10 : 1 transformer supplies power to a 9Ω load. If the primary input voltage has a rms value of 200 volt and forward diode resistance is 0.2Ω and transformer secondary resistance is 0.8Ω , determine :
 - a) I_L (dc)
 - b) rms ripple voltage
 - c) efficiency.
6. What are the advantages and limitations of I.C. technology ?



GROUP - C

(Long Answer Type Questions)

Answer any *three* of the following.

3 × 15 = 45

7. a) Distinguish between *n*-channel and *p*-channel MOSFETs. 5
- b) What are the different types of MOSFETs ? Sketch the structure of a *p*-channel enhancement MOSFET and explain its working. 10
8. a) What are the characteristics of an ideal OP-AMP ? Draw the circuit symbol of a basic OP-AMP. 3 + 2
- b) Draw the schematic diagram and derive the expression for the output voltage for an ideal non-inverting OP-AMP and an adder. 5 + 5
9. a) What is feedback ? Define negative feedback. 3
- b) Draw the block diagram of a negative feedback amplifier and derive the expression for the voltage gain with a feedback factor β . 7
- c) An amplifier has voltage gain of - 500. This gain is reduced to - 100 when negative feedback is applied. Determine the feedback factor β and express the amount of feedback in dB. 5
10. a) Derive expressions for current gain and input resistance of a transistor amplifier operation in the CE mode using *h*-parameters. 8
- b) A common-emitter transistor amplifier circuit has the following characteristics :
 $h_{ie} = 1000 \, \Omega$, $h_{re} = 2.5 \times 10^{-4}$, $h_{fe} = 50$ and $h_{oe} = 25 \times 10^{-6} \, \text{A/V}$. Load resistance $R_L = 10 \, \text{K}\Omega$ and source resistance is $100 \, \Omega$. Find the current gain and input resistance. 7
11. a) Give the two-transistor representation of a SCR. 3
- b) Explain the working principle of SCR. 7
- c) Draw the voltage-current characteristics of a TRIAC. 5